

产品规格书

SPECIFICATION

CUSTOMER 客户: _____
PRODUCT 产品: _____ SAW FILTER _____
MODEL NO 型号: _____ KH-SAWF158A _____
MARKING 印字: _____ ● B049 _____
PREPARED 编制: _____ CHECKED 审核: _____
APPROVED 批准: _____ D A T E 日期: _____ 2017-6-30 _____

客户确认 CUSTOMER RECEIVED:		
审核 CHECKED	批准 APPROVED	日期 DATE

深圳市金航标电子有限公司
SHENZHEN KINGHELM ELECTRON CO., LTD.

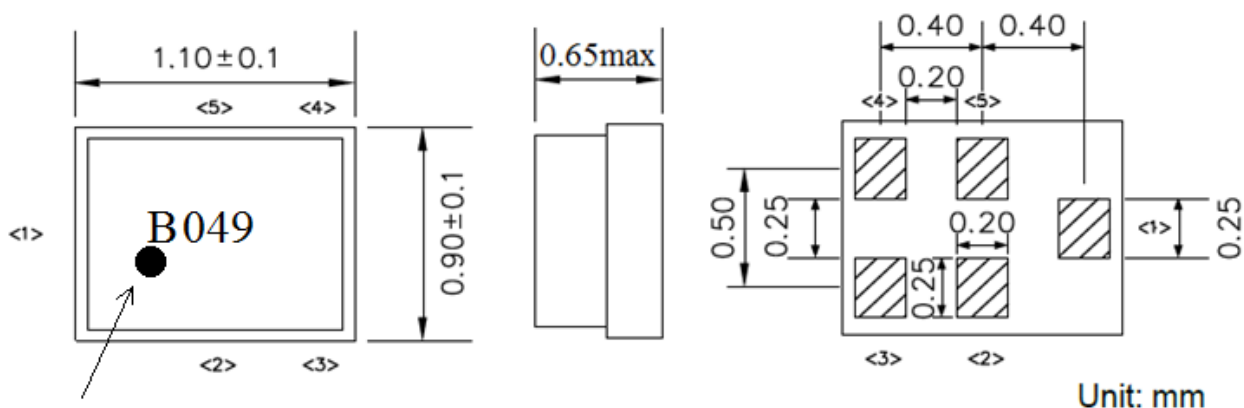
更改历史记录 History Record

更改日期 Date	规格书编号 Spec. No.	产品型号 Part No.	客户产品型号 Customer No.	更改内容描述 Modify Content	备注 Remark
2015-7-1	SP00	KH-SAWF158A		NEW SPEC.	
2016-02-16	SP01	KH-SAWF158A		Add attenuation 2010 - 2025 MHz 2300 - 2400 MHz	
2016-4-11	SP02	KH-SAWF158A		Complete specifications. Add product application, reliability and other information.	
2016-8-23	SP03	KH-SAWF158A		Change carrier tape size. Carrier tape encryption.	10. TAPE SPECIFICATIONS [Figure 1] Carrier Tape Dimensions
2016-8-31	SP04	KH-SAWF158A		Insertion Loss in 1574.42~1576.42 MHz, from 1.5max to 1.2max.	5. Electrical specifications
2016-11-25	SP05	KH-SAWF158A		Correction device size. Thickness changed from 0.5max. to 0.65max	2. Package Dimension
2017-6-30	SP06	KH-SAWF158A		Add dot marking.	

1. Application

- Low-loss RF GPS + COMPASS + GLONASS filter
- Usable passband: 2.0 MHz for GPS, 4.092 MHz for COMPASS and 8.34 MHz for GLONASS
- Impedance 50 ohm input and output
- Unbalanced to unbalanced operation
- RoHS compatible

2. Package Dimension (PKG SIZE 1.1 x 0.9mm)



Dot Marking

Unit: mm

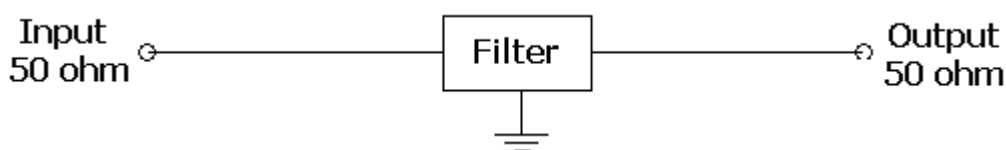
Pin configuration

- 1. Input
- 4. Output
- 2,3,5 To be grounded

3. Maximum Rating

Items	Conditions
Operation temperature rang	-30°C ~ +85°C
Storage temperature rang	-40°C ~ +85°C
ESD voltage	ESD(MM) : 50VDC
Sensitive discharge device	ESD(HBM) : 175VDC
DC Voltage VDC	5V
Max Input Power	15dBm 2000h
Moisture Sensivity Level	MSL 2

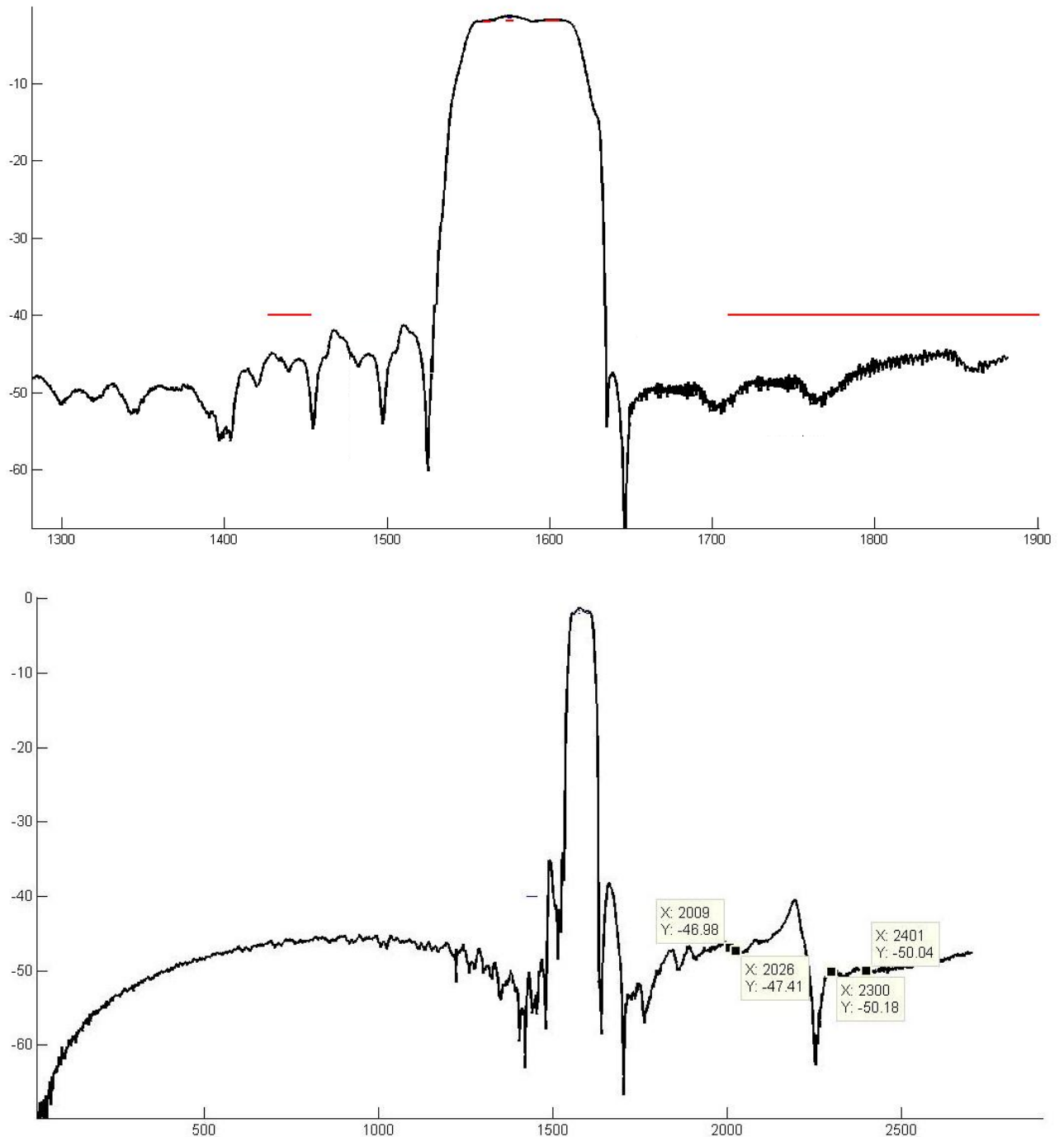
4. Test Circuit



5. ELECTRICAL SPECIFICATION

	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	-	1582.4	-
Insertion Loss				
1574.42~1576.42 MHz			1.0	1.2
1559.05~1563.15 MHz	dB		1.8	2.0
1573.37~1577.47 MHz			1.5	2.0
1597.78~1605.66 MHz			1.8	2.0
Pass band ripple				
1574.42~1576.42 MHz			0.2	1.0
1559.05~1563.15 MHz	dB		0.3	1.0
1573.37~1577.47 MHz			0.2	1.0
1597.78~1605.66 MHz			0.4	1.0
VSWR				
1574.42~1576.42 MHz			1.2	2.0
1559.05~1563.15 MHz	dB		1.6	2.0
1573.37~1577.47 MHz			1.4	2.0
1597.78~1605.66 MHz			1.6	2.0
Group delay ripple				
1597.78~1605.66 MHz	ns		4	12
Attenuation				
10~824 MHz		47	51	
824~925 MHz		47	51	
1427~1453 MHz		40	45	
1710~1785 MHz		40	45	
1850~1910 MHz		40	44	
1920~1980 MHz	dB	39	44	-
2010~2025 MHz		43	47	
2300~2400 MHz		46	50	
2400~2500 MHz		43	45	
2500~2570 MHz		37	42	
2600~3000 MHz		30	38	
4900~5850 MHz		15	24	
Input/Output Impedance	Ohms		50	

6. Frequency Characteristics



7. ENVIRONMENTAL CHARACTERISTICS

7.1 High temperature exposure

Subject the device to +85°C for 16 hours. Then release the filter into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 5.

7.2 Low temperature exposure

Subject the device to -40°C for 16 hours. Then release the device into the room conditions

for 24 hours prior to the measurement. It shall fulfill the specifications in 5.

7.3 Temperature cycling

Subject the device to a low temperature of -40°C for 30 minutes. Following by a high temperature of $+85^{\circ}\text{C}$ for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in 5.

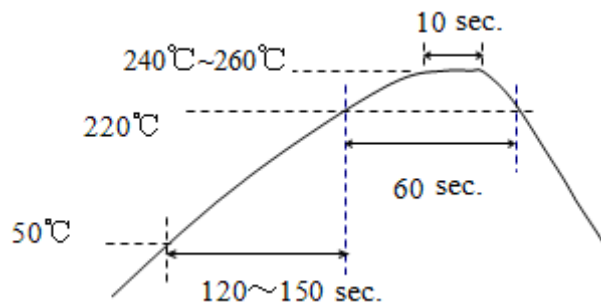
7.4 Resistance to solder heat

- 1、immerge the solder bath at 260°C for 10 sec.
- 2、 the iron at 370°C for 3 sec

7.5 Solderability

Submerge the device terminals into the solder bath at $245^{\circ}\text{C} \pm 5^{\circ}\text{C}$ for 5s, More than 95% area of the soldering pad must be covered with new solder. It shall meet the specifications in 5.

7.6 Reflow soldering



The specimen shall be passed through the reflow furnace with the condition shown in the above profile for 1 time.

The specimen shall be stored at standard atmospheric conditions for 1h, after which the measurement shall be made. Test board shall be 1.6 mm thick. Base material shall be glass fabric base epoxy resin.

7.7 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in 5.

7.8 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in 5.

8. REMARK

8.1 Static voltage

Static voltage between signal load & ground may cause deterioration & destruction of the component. Please avoid static voltage.

8.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

8.3 Soldering

Only pad component may be solded. Please avoid soldering another part of component.

9. Packing

9.1 Dimensions

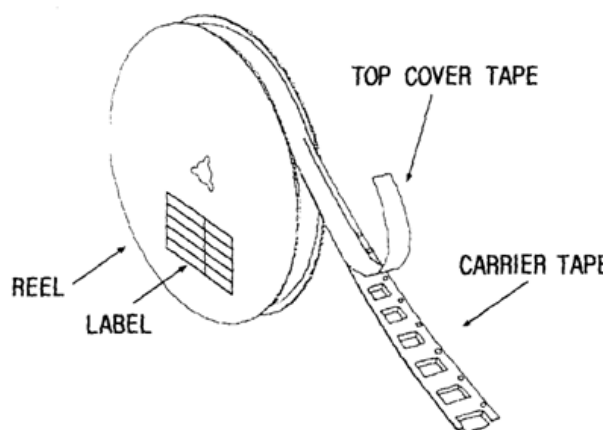
- (1) Carrier Tape: Figure 1
- (2) Reel: Figure 2
- (3) The product shall be packed properly not to be damaged during transportation and storage.

9.2 Reeling Quantity

10000 pcs/reel ϕ 178mm

9.3 Taping Structure

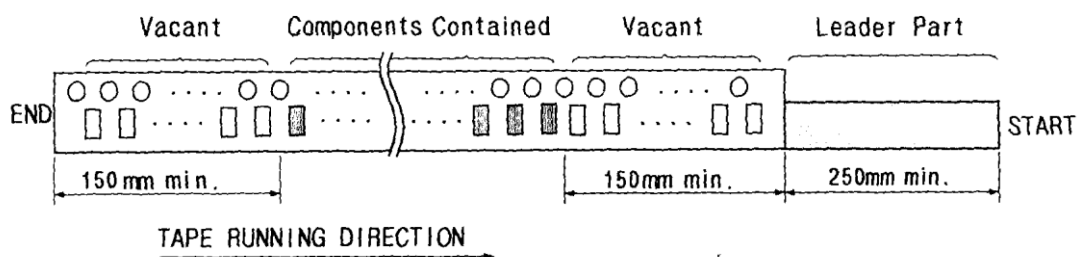
- (1) The tape shall be wound around the reel in the direction shown below.



- (2) Label

Device Name	
Marking	
User Product Name	
Quantity	
Lot No.	

- (3) Leader part and vacant position specifications.

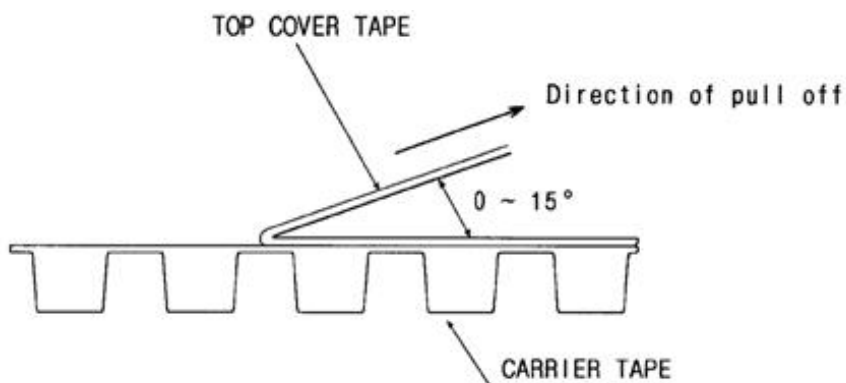


10. TAPE SPECIFICATIONS

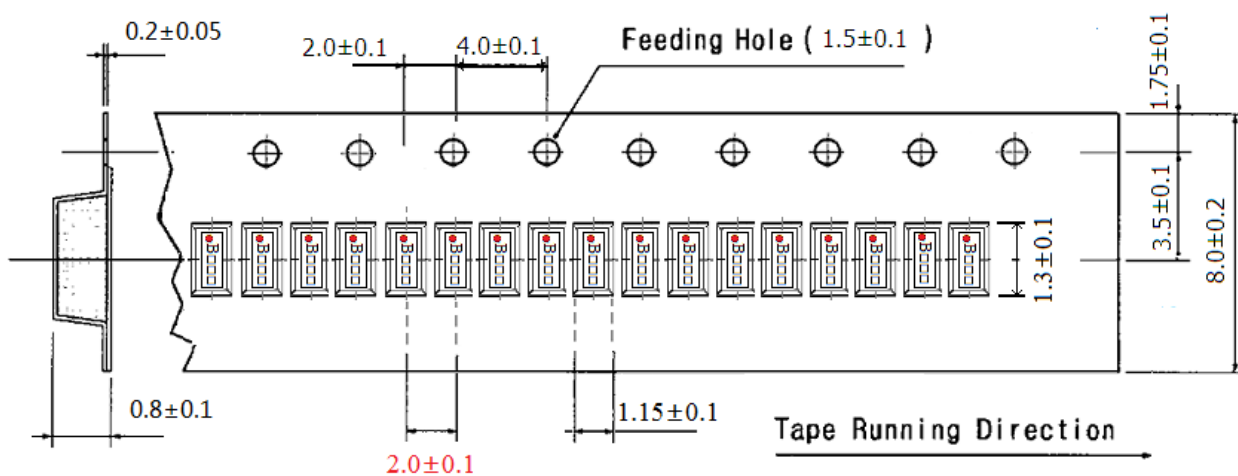
10.1 Tensile Strength of Carrier Tape: 4.4N/mm width

10.2 Top Cover Tape Adhesion (See the below figure)

- (1) pull off angle: 0~15°
- (2) speed: 300mm/min.
- (3) force: 20~70g



[Figure 1] Carrier Tape Dimensions



Prior to the size of 4.0 ± 0.1 , after encryption, modified to 2.0 ± 0.1 .

[Figure 2] 10000 pcs/reel ϕ 178mm

